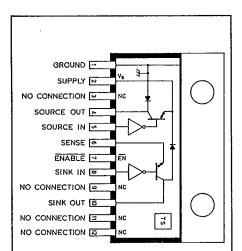
# 24955-2

十-52-1

#### HIGH-CURRENT HALF-BRIDGE POWER DRIVER



Dwg. PP-023

ABSOLUTE MAXIMUM RATINGS at  $T_r \le 150^{\circ}C$ 

Supply Voltage, V <sub>S</sub>
Output Current, I <sub>OUT</sub> ±6.0 A
input Voltage, V <sub>IN</sub>
Sense Voltage, V <sub>SENSE</sub>
Package Power Dissipation,
P <sub>D</sub> See Graph
Operating Temperature Range,
T <sub>A</sub> 20°C to + 85°C
Storage Temperature Range,
T -55°C to + 150°C

Output current rating may be limited by duty cycle, ambient temperature, and heat sinking. Under any set of conditions, do not exceed the specified output current rating or a junction temperature of +150°C.

The UDN2955W–2 half-bridge power driver combines a highcurrent, half-bridge power driver with low-level control and protection circuitry. For PWM applications there are provisions for output current sensing and an ENABLE (active low) input. The output can source or sink up to 6 A continuously. This device features a minimum breakdown and sustaining voltage of 40 V. It can be used in pairs for fullbridge operation or in triplets for 3-phase brushless dc motors.

Protection is included which shuts down the device during overtemperature conditions caused by loss of cooling; internal flyback and clamp diodes are included for switching inductive loads. Internal logic lockout and delays prevent potentially destructive crossover currents. The logic inputs are compatible with TTL and 5 V CMOS logic systems.

A similar device, excluding the ENABLE and output current sensing provision, in a 5-lead TO-220 style package, is the UDN2951Z-2.

The UDN2955W–2 is supplied in a 12-lead power-tab single in-line plastic package. The tab is at ground potential, allowing multiple devices to share a common heat sink.

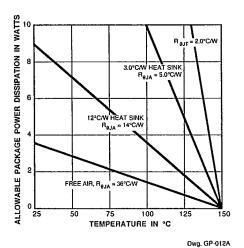
#### FEATURES

- ± 6 A Continuous Output Current
- Output Voltage to 40 V
- Internal Thermal Shutdown
- TTL and 5 V CMOS Compatible Inputs
- Integral Transient-Suppression Diodes

Always order by complete part number: [UDN2955W-2].

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#### 



FUNCTIONAL BLOCK DIAGRAM

SOURCE (3)

THERMAL SHUTDOWN

SINK (8)

GROUND (1)

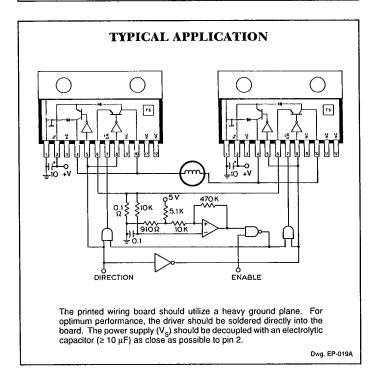
SENSE

Dwg. FP-009

TRUTH TABLE

	INPUTS	OUTPUTS			
ENABLE	SOURCE	SINK	SOURCE	SINK	
Low	Low	Low	OFF	ON	
Low	Low	Hìgh	OFF	OFF	
Low	High	Χ	ON	OFF	
High	Х	Х	OFF	OFF	

X = Irrelevant



## 2055=2 THEOH-CUIRUNA TUNARABRID CALAROXMURID RAMBR

1700C V 40 V

### ELECTRICAL CHARACTERISTICS at $T_A = +25$ °C, $T_J \le +150$ °C, $V_S = 40$ V

	Symbol			Limits			
Characteristic		Test Conditions	Min.	Тур.	Max.	Units	
Functional Supply Range	V <sub>s</sub>		10		40	٧	
Output Leakage Current	I <sub>CEX</sub>	SINK <sub>OUT</sub> = 40 V, SOURCE <sub>IN</sub> = 0.8 V, SINK <sub>IN</sub> = 2.0 V		<1.0	50	μА	
		SOURCE <sub>OUT</sub> = 0 V, SOURCE <sub>IN</sub> = 0.8 V, SINK <sub>IN</sub> = 2.0 V	-	<-1.0	- 50	μА	
Output Sustaining Voltage	V <sub>CE(sus)</sub>	I <sub>OUT</sub> = ± 6.0 A, L =10 mH	40	_		٧	
Output Saturation Voltage	V <sub>CE(SAT)</sub>	SINK <sub>OUT</sub> = 5.0 A			1.5	V	
		SINK <sub>OUT</sub> = 6.0 A	_	_	2.0	V	
		SOURCE <sub>OUT</sub> = -5.0 A	-		2.0	V	
		SOURCE <sub>OUT</sub> = -6.0 A			2.5	V	
Input Voltage	Logic 1	SOURCE <sub>IN</sub> or SINK <sub>IN</sub>	2.0			V	
	Logic 0	SOURCE <sub>IN</sub> or SINK <sub>IN</sub>		_	0.8	٧	
Input Current	Logic 1	SOURCE <sub>IN</sub> or SINK <sub>IN</sub> = 2.0 V		3.0	10	μА	
	Logic 0	SOURCE <sub>IN</sub> or SINK <sub>IN</sub> = 0.8 V	_	-1.0	-10	μА	
Propagation Delay	t <sub>PHL</sub>	Sink Driver (includes Turn-On Delay)	<u> </u>	2.5	_	μs	
		Source Driver	_	2.5		μs	
	t <sub>PLH</sub>	Sink Driver	_	0.2	_	μs	
		Source Driver (includes Turn-On Delay)	_	2.5		μs	
Supply Current	I <sub>S(ON)</sub>	SOURCE <sub>IN</sub> = 2.0 V		10	15	mA	
		SOURCE <sub>IN</sub> = SINK <sub>IN</sub> = 0.8 V	_	20	25	mA	
	I <sub>S(OFF)</sub>	SOURCE <sub>IN</sub> = 0.8 V, SINK <sub>IN</sub> = 2.0 V	-	8.0	10	mA	
Flyback Diode Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 6.0 A	<del>  -</del> -		2.8	V	
Clamp Diode Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 6.0 A	1-	_	2.1	٧	
Diode Leakage Current	I <sub>R</sub>	Each Diode, V <sub>R</sub> = 40 V	<u> </u>	<1.0	50	μА	
Thermal Shutdown	T			165		°C	

NOTE: Typical Data is given for circuit design information only.

Negative current is defined as coming out of (sourcing) the specified device pin.

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